# **ACTIVE SEMICONDUCTIOR FUNCTIONS**

	Reference	Type	Function
AF Circuit			
	IC200 IC250 IC251	Dream T1 NJM2068MD SA572D	AF-amplifier and tone-Generator IC OP amplifier Compander IC
RF Circuit			
	Q101 Q102-103 Q104 Q106 IC5 IC8	2SC4226 2SC5226 2SC4738 DTA114YKA MB1511PFV NJU6366	RF-Buffer RF Amplifier RF-Power Controller RF-Switch PLL IC PLL/ 9MHz Ref. Oscillator

ACTIVE SEMICONDUCTORS FCCID: JFZT310D

### APPENDIX 2

### CIRCUITS AND DEVICES TO STABILIZE FREQUENCY

Operating frequency is determined and stabilized by a PLL circuit using a 9MHz crystal-Controlled reference oscillator.

### CIRCUIT TO SUPPRESS SPURIOUS RADIATION AND CONTROL MODULATION

#### **AUDIO CIRCUIT**

The audio signal is injected via the HRS connector into the audio circuit composed of the op amp in IC200, Dream T1, then compressed via the compandor circuit composed of the op amp IC250, and compander IC251 at a 2:1 ratio and is pre-emphasized by AF amp in IC200. The level of the output signal is controlled by the pot VR201 which is injected into the VCO, VCO100.

Output level of the 32.15kHz tone signal that produced by IC200 is controlled by the pot VR200 which is mixed with the audio output signal and injected into the VCO, VCO100

#### **MODULATOR CIRCUIT**

The modulator circuit is a direct FM type built around the VCO, VCO100. The modulated output from the VCO is sent to the RF final amplifier which boosts the output to a nominal level of 10mW at RF output low setting or 30mW at RF output Hi setting.

### RF PRE-AMPLIFIER & FINAL AMPLIFIER

The 3 transistor amplifier stages, using 2SC4226 and 2SC5225 type transistors, culminating with a normal transmitter output of 10mW at RF output low setting and 30mW at RF output Hi setting. The output filter comprised of L104, L L105, L106 L107, C132, C133, C134 & C135suppresses the output harmonics and the output to the antenna.